L	Hits	Search Text	DB	Time stamp
Number				
1	28	(US-5866933-\$ or US-5278105-\$ or	USPAT;	2004/11/03
		US-5475251-\$ or US-4672221-\$ or	US-PGPUB;	18:05
		US-5369299-\$ or US-5468990-\$ or	JPO	
		US-5050123-\$ or US-5061978-\$ or		
		US-5488251-\$ or US-5821582-\$ or		
1		US-6326675-\$ or US-6072328-\$ or US-6198155-\$ or US-5907008-\$ or	1	
		US-5717224-\$ or US-5702849-\$ or		
]		US-5622787-\$ or US-6281266-\$ or		}
		US-6163062-\$ or US-6259495-\$ or		
		US-5990491-\$ or US-RE37591-\$ or		
1		US-6380561-\$ or US-5966193-\$ or		
		US-6031593-\$).did. or	·	
		(US-20010003374-\$).did. or (JP-61296738-\$		
		or JP-11038221-\$).did.		
2	1	"2002024148"	USPAT;	2004/11/03
			US-PGPUB;	18:05
	_		JPO	0004/55/00
3	1	"6413847"	USPAT;	2004/11/03
			US-PGPUB;	18:05
4	4	"6207479"	JPO	2004/11/02
]]	4	020/9/9	USPAT;	2004/11/03
			US-PGPUB; JPO	18:05
5	19	"5930663"	USPAT;	2004/11/03
1	•		US-PGPUB;	18:06
			EPO; JPO	-0.00
6	18	"5336624"	USPAT;	2004/11/03
			US-PGPUB;	18:07
	,		EPO; JPO	
7 .	0	jp0361147551a	USPAT;	2004/11/03
			US-PGPUB;	18:08
1_			EPO; JPO	
8	1	jp361147551a	USPAT;	2004/11/03
			US-PGPUB;	18:13
9	8	"5345105"	EPO; JPO	2004/11/02
	8	2242102	USPAT; US-PGPUB;	2004/11/03 18:12
			EPO; JPO	10.12
10	5	"5861652"	USPAT;	2004/11/03
		•••	US-PGPUB;	18:12
			EPO; JPO	
11	10	"4434361"	USPAT;	2004/11/03
			US-PGPUB;	18:12
		<u> </u>	EPO; JPO	
12	7	"6137318"	USPAT;	2004/11/03
			US-PGPUB;	18:12
13	ا _ ا	"6014052"	EPO; JPO	2004/11/22
13	5	"6014052"	USPAT;	2004/11/03
			US-PGPUB; EPO; JPO	18:12
14	8		USPAT;	2004/11/03
			US-PGPUB;	18:12
			EPO; JPO	20.16
15	1	jp410270562a	USPAT;	2004/11/03
		, <u></u>	US-PGPUB;	18:18
ļ			EPO; JPO	
16	2	"5873846"	USPAT;	2004/11/03
			US-PGPUB;	18:18
l			EPO; JPO	
17	27	"5866933"	USPAT;	2004/11/03
,			US-PGPUB;	18:19
10	[WF072275#	EPO; JPO	
18	11	"5973375"	USPAT;	2004/11/03
			US-PGPUB;	18:19
19	13	"6117762"	EPO; JPO	2004/11/02
1 2	13	011//02	USPAT;	2004/11/03
			US-PGPUB;	18:19
L	L		EPO; JPO	

			·,	
20	90	"2002024148" "6413847" "6207479"	USPAT;	2004/11/03
		"5930663" "5336624" jp361147551a	US-PGPUB;	18:20
		"5345105" "5861652" "4434361" "6137318"	EPO; JPO	
	-	"6014052" "5998858" jp410270562a		
		"5873846" "5866933" "5973375" "6117762"		}
_	826		USPAT;	2002/07/08
		conductive near1 shielding	US-PGPUB;	08:16
			EPO; JPO;	33.23
			L	
•	م م		DERWENT	2002/10/25
· -	826	·	USPAT;	2002/10/25
		conductive near1 shielding	US-PGPUB;	15:52
			EPO; JPO;	
			DERWENT	
-	46		USPAT;	2002/07/08
		conductive nearl shielding) and	US-PGPUB;	08:56
		(semiconductor adj device)	EPO; JPO;	1
			DERWENT	1
_	0	20010041431.URPN.	USPAT	2002/07/08
ŀ			}	08:20
Ĭ _	12	("4268911" "4603381" "4766516"	USPAT	2002/07/08
	12	"4843026" "4885617" "5010032") SERI	08:24
		"5187122" "5465005" "5661085"		00.24
	_	"5804470" "5821150" "5834356").PN.		2002/07/02
_	0	6326675.URPN.	USPAT	2002/07/08
				08:27
-	4	5866933.URPN.	USPAT	2002/07/08
	- 1			08:32
. –	42	("3946426" "4139864" "4164461"	USPAT	2002/07/08
		"4267578" "4291391" "4314268"	}	08:33
		"4471376" "4581628" "4583011"		
		"4603381" "4623255" "4727493"		
		"4766516" "4799096" "4821085"		
		"4975756" "5030796" "5050123"		
		"5061978" "5065208" "5068697"	ł	
		"5070378" "5101121" "5117276"		l i
		"5132571" "5138197" "5146117"		
		"5202591" "5227649" "5231299"	ŀ	
		"5302539" "5308682" "5309015"		
	į .	"5336624" "5354704" "5369299"	*	
		"5376577" "5399441" "5441902"		
	:	"5468990" "5475251" "5539224").PN.		
_	307	(reverse nearl engineering) (opaque nearl	USPAT;	2002/07/08
		conductive near1 shielding) and	US-PGPUB;	13:18
		((semiconductor adj (chip device))	EPO; JPO;	
		(integrated adj circuit))	DERWENT	
-	261		USPAT;	2002/07/08
		nearl conductive nearl shielding) and	US-PGPUB;	08:58
		((semiconductor adj (chip device))	EPO; JPO;	
		(integrated adj circuit))) not ((reverse	DERWENT	
		nearl engineering) (opaque nearl		
		conductive near1 shielding) and	1	
		(semiconductor adj device))		
_	_		IICDAM.	2002/07/09
_	0	(((reverse near1 engineering) (opaque	USPAT;	2002/07/08
		nearl conductive nearl shielding) and	US-PGPUB;	08:59
		((semiconductor adj (chip device))	EPO; JPO;	
		(integrated adj circuit))) not ((reverse	DERWENT	
		nearl engineering) (opaque nearl		
		conductive near1 shielding) and		[
		(semiconductor adj device))) and		
		(blocking near (film layer))		
-	4	(((reverse nearl engineering) (opaque	USPAT;	2002/07/08
-		nearl conductive nearl shielding) and	US-PGPUB;	09:00
		((semiconductor adj (chip device))	EPO; JPO;	"""
		(integrated adj circuit))) not ((reverse	DERWENT	
			DEKMENT	
		nearl engineering) (opaque nearl	1.	}
		conductive near1 shielding) and	1	
<u>t</u>		(semiconductor adj device))) and	}	1
[:		(aluminum adj oxide)	1	1

		, , , , , , , , , , , , , , , , , , , 		
-	57	(((reverse nearl engineering) (opaque	USPAT;	2002/07/08
		nearl conductive nearl shielding) and	US-PGPUB;	09:00
1		((semiconductor adj (chip device))	EPO; JPO;	
İ		(integrated adj circuit))) not ((reverse	DERWENT	ŀ
Ì	ļ	nearl engineering) (opaque nearl	ļ	ŀ
·		conductive near1 shielding) and		
		(semiconductor adj device))) and blocking		
-	0	6326675.URPN.	USPAT	2002/07/08
				09:42
-	0	6198155.URPN.	USPAT	2002/07/08
				09:42
-	7	("4243427" "4849296" "5203915"	USPAT	2002/07/08
		"5221558" "5399441" "5591680"		09:44
		"5744244").PN.		
-	0	6198155.URPN.	USPAT	2002/07/08
l				09:44
-	9	5468990.URPN.	USPAT	2002/07/08
				09:45
-	2	5821582.URPN.	USPAT	2002/07/08
		,		09:48
-	9	("4030952" "5030796" "5070386"	USPAT	2002/07/08
		"5109267" "5231299" "5308682"		09:48
		"5337274" "5369299" "5468990").PN.		j l
-	7	("4030952" "5030796" "5070386"	USPAT	2002/07/08
	ļ	"5109267" "5231299" "5308682"		09:50
		"5337274").PN.		
-	9	5468990.URPN.	USPAT	2002/07/08
	İ			09:51
-	2	("4030952" "5109267").PN.	USPAT	2002/07/08
	İ			09:51
-	16	5369299.URPN.	USPAT	2002/07/08
				09:51
-	9	5061978.URPN.	USPAT	2002/07/08
				10:21
-	5	("4291326" "4419533" "4621275"	USPAT	2002/07/08
		"4654536" "4672221").PN.		10:23
_	13	5475251.URPN.	USPAT	2002/07/08
				10:25
-	35	5278105.URPN.	USPAT	2002/07/08
				10:27
-	7	("4711701" "4916514" "4949162"	USPAT	2002/07/08
		"49635 <u>0</u> 1" "4973562" "5032890"		10:31
		"5132237").PN.		
_	17	4672221.URPN.	USPAT	2002/07/08
				10:32
-	832	reverse nearl engineering) (opaque nearl	USPAT;	2002/07/08
		conductive near1 shielding	US-PGPUB;	13:17
			EPO; JPO;	
		, , , , , , , , , , , , , , , , , , ,	DERWENT	
-	307	(reverse near1 engineering) (opaque near1	USPAT;	2002/10/25
		conductive near1 shielding) and	US-PGPUB;	15:53
		((semiconductor adj (chip device))	EPO; JPO;	
		(integrated adj circuit))	DERWENT	
_	1	((reverse nearl engineering) (opaque	USPAT;	2002/10/25
•		near1 conductive near1 shielding) and	US-PGPUB;	15:55
•		((semiconductor adj (chip device))	EPO; JPO;	
		(integrated adj circuit))) and (light	DERWENT	<u> </u>
		near (blocking shielded shielding		
<u> </u>	1.2	shield))	IICDAM -	2002/07/00
-	13	(US-6326675-\$ or US-6198155-\$ or	USPAT;	2002/07/08
	1	US-5866933-\$ or US-5475251-\$ or	US-PGPUB	13:20
	}	US-5278105-\$ or US-5468990-\$ or		·
		US-5369299-\$ or US-5061978-\$ or]
		US-5050123-\$ or US-5821582-\$ or		
		US-4672221-\$ or US-5488251-\$).did. or		
	_	(US-20010003374-\$).did.	HCDAM.	2002/07/00
_	2	(reverse nearl engineering) (opaque nearl	USPAT;	2002/07/08
		conductive nearl shielding) and (light	US-PGPUB;	13:20
		near (blocking shielded shielding	EPO; JPO;	
L	L	shield))	DERWENT	[

=	46749	(light near (blocking shielded shielding shield))	USPAT; US-PGPUB;	2002/07/09
		Sileta,,	EPO; JPO; DERWENT	09.10
_	2	((light near (blocking shielded shielding shield))) and (reverse near engineering)	USPAT; US-PGPUB;	2002/07/08 13:23
	2	//3:	EPO; JPO; DERWENT	2002/07/00
_	2	((light near (blocking shielded shielding shield))) and (reverse nearl engineering)	USPAT; US-PGPUB; EPO; JPO;	2002/07/08
_	39713	(light adj (blocking shielded shielding shield))	DERWENT USPAT; US-PGPUB;	2002/07/08 13:29
	10		EPO; JPO; DERWENT	2002/07/00
_	10	<pre>((light adj (blocking shielded shielding shield))) near3 (corrosion adj resistance)</pre>	USPAT; US-PGPUB; EPO; JPO;	2002/07/08
-	40	((light adj (blocking shielded shielding shield))) with (aluminum adj oxide)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/07/08 13:37
-	2	5702849.URPN.	DERWENT USPAT	2002/07/08
-	8	("3740280" "4722878" "4981771" "5049461" "5115465" "5154949"	USPAT	2002/07/08 13:59
_	9	"5181132" "5233211").PN. 5061978.URPN.	USPAT	2002/07/08
_	138	(silicon adj nitride) near3 corrosion	USPAT; US-PGPUB; EPO; JPO;	2002/07/09 08:55
_ ·	5	((silicon adj nitride) near3 corrosion) and ((passivation plasma) near1 nitride)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/07/09 08:55
_	2	((passivation plasma) near1 nitride) near3 corrosion	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/07/09 09:04
_	0	((passivation plasma) near nitride) near3 (silicon adj nitride) near3 corrosion	DERWENT USPAT; US-PGPUB;	2002/07/09
	. 0	_	EPO; JPO; DERWENT	2002/07/00
	, 0	(((passivation plasma) near nitride) near3 (silicon adj nitride)) near3 corrosion	USPAT; US-PGPUB; EPO; JPO;	2002/07/09 09:03
_	0	(((passivation plasma) near1 nitride) near3 (silicon adj nitride)) near3 corrosion	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/07/09 09:03
-	2	((passivation plasma) near nitride) near3	DERWENT USPAT; US-PGPUB;	2002/07/09
			EPO; JPO; DERWENT	
	3	((passivation plasma) near nitride) near4 corrosion	USPAT; US-PGPUB; EPO; JPO;	2002/07/09 09:05
_	9	((passivation plasma) near nitride) with corrosion	DERWENT USPAT; US-PGPUB;	2002/07/09 09:05
_	6	(((passivation plasma) near nitride) with	EPO; JPO; DERWENT USPAT;	2002/07/09
		corrosion) not (((passivation plasma) near nitride) near4 corrosion)	US-PGPUB; EPO; JPO; DERWENT	09:06

-	585	((light adj (blocking shielded shielding shield))) and (aluminum adj oxide)	USPAT; US-PGPUB;	2002/07/09
			EPO; JPO; DERWENT	
_	39738	(light adj (blocking shielded shielding	USPAT;	2002/07/09
		shield))	US-PGPUB;	09:16
	İ		EPO; JPO; DERWENT	,
-	1078	(passivation plasma protective) near4	USPAT;	2002/07/09
		(aluminum adj oxide)	US-PGPUB; EPO; JPO;	09:18
			DERWENT	
-	1912	(passivation plasma protective cover	USPAT;	2002/07/09
		covering covered) near4 (aluminum adj	US-PGPUB; EPO; JPO;	09:18
			DERWENT	
=	15	((light adj (blocking shielded shielding shield))) and ((passivation plasma	USPAT; US-PGPUB;	2002/07/09
		protective) near4 (aluminum adj oxide))	EPO; JPO;	
_	31	((light adj (blocking shielded shielding	DERWENT USPAT;	2002/07/09
	31	shield))) and ((passivation plasma	US-PGPUB;	09:19
		protective cover covering covered) near4	EPO; JPO;	
_	. 0	(aluminum adj oxide)) (light adj blocking adj film) near6	DERWENT US-PGPUB	2002/07/09
	1.7	(principal adj part)		10:43
_	17	((light adj (blocking shielded shielding shield))) near3 (tantalum niobium)	USPAT; US-PGPUB;	2002/07/09
			EPO; JPO;	
_	903	reverse near1 engineering) (opaque near1	DERWENT USPAT;	2002/10/25
		conductive near1 shielding	US-PGPUB;	15:53
			EPO; JPO; DERWENT	
-	348	(reverse nearl engineering) (opaque nearl	USPAT;	2002/10/25
		conductive near1 shielding) and ((semiconductor near1 (chip package	US-PGPUB; EPO; JPO;	15:54
		device)) (integrated adj circuit))	DERWENT	
-	1	((reverse nearl engineering) (opaque	USPAT;	2002/10/25
		nearl conductive nearl shielding) and ((semiconductor nearl (chip package	US-PGPUB; EPO; JPO;	15:56
		device)) (integrated adj circuit))) and	DERWENT	
		(light near1 (blocking shielded shielding shield))		
_	6	((reverse nearl engineering) (opaque	USPAT;	2002/10/25
		nearl conductive nearl shielding) and ((semiconductor nearl (chip package	US-PGPUB; EPO; JPO;	15:56
		device)) (integrated adj circuit))) and	DERWENT	
		(light with (blocking shielded shielding shield))		
	L	DILECTA	l	L